The Possible integration of the Double Perovskite Ba₂XSbO₆ (X=Sc,In) Compounds in solar cells technologies

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Abstract: In this work, we have comprehensively investigated DFT investigation on optoelectronic, properties of Ba₂InSbO₆ and Ba₂ScSbO₆ double perovskite oxides. The structural optimization was carried out using generalized gradient approximation (PBEsol-GGA). Moreover, the new Becke-Johnson (new-mBJ) was utilized in the framework of PBEsol GGA to precisely evaluate the electronic bandgaps. the material demonstrates a direct bandgap of 1.62 eV and 4.02 eV for Ba₂InSbO₆ and Ba₂ScSbO₆ respectively. Based on these bandgap values and the optic properties, the studied materials illustrate different properties, signifying different possible applications. Specially for solar cell technologies and light emitting elements.

Keywords: Perovskites, Solar cell, Energy.